



Subject card

Subject name and code	Basics of Microelectronics, PG_00048079						
Field of study	Electronics and Telecommunications						
Date of commencement of studies	October 2023	Academic year of realisation of subject			2025/2026		
Education level	first-cycle studies	Subject group			Optional subject group Subject group related to scientific research in the field of study		
Mode of study	Full-time studies	Mode of delivery			at the university		
Year of study	3	Language of instruction			Polish		
Semester of study	5	ECTS credits			3.0		
Learning profile	general academic profile	Assessment form			exam		
Conducting unit	Department of Microelectronic Systems -> Faculty of Electronics, Telecommunications and Informatics						
Name and surname of lecturer (lecturers)	Subject supervisor		dr hab. inż. Piotr Płotka				
	Teachers		dr hab. inż. Piotr Płotka				
Lesson types and methods of instruction	Lesson type	Lecture	Tutorial	Laboratory	Project	Seminar	SUM
	Number of study hours	30.0	0.0	0.0	0.0	0.0	30
	E-learning hours included: 0.0						
Learning activity and number of study hours	Learning activity	Participation in didactic classes included in study plan		Participation in consultation hours		Self-study	SUM
	Number of study hours	30		3.0		42.0	75
Subject objectives	Building of knowledge and skills for selection of a family and of a technology of application specific integrated circuits, appropriately for the required functionality. Building skills for designing basic cells and subcircuits of integrated circuits.						

Learning outcomes	Course outcome	Subject outcome	Method of verification
	[K6_W33] Knows programming languages and equipment description languages, as well as methods for the synthesis of combinational and sequential circuits and programmable systems	Student specifies basic constructions and element layouts of logical gates in different families of integrated circuits, with respect to parasitic elements. Student specifies basic constructions and element layouts of flip-flops in different families of integrated circuits. Student specifies basic constructions and element layouts of memory cells and blocks in different families of integrated circuits.	[SW1] Assessment of factual knowledge
	[K6_W32] Knows the parameters, functions and methods of analysis, design and optimization of analogue and digital circuits and electronic systems	Student knows properties of the main families of integrated circuits in relation to the applied elements and technologies. He knows basic constructions and element layouts of logical gates and flip-flops in various families of integrated circuits. Student describes main fabrication steps of CMOS and BiCMOS integrated circuits. Student describes main technological processes used in fabrication of integrated circuits. Student describes currently developed technologies which can replace or complement silicon technologies in future.	[SW1] Assessment of factual knowledge
	[K6_U06] can analyse the operation of components, circuits and systems related to the field of study, measure their parameters and examine technical specifications	Student selects an appropriate family of integrated circuits with respect to the required elements, technologies and methods of construction. In relation to the selected family of integrated circuits he applies basic circuit designs and photomask layouts of combinatory subcircuits, flip-flop blocks as well as memory blocks. He synthesizes combinatory circuits. He considers influence of element scaling of integrated circuits on properties of transistors and influence of transistor characteristics on properties of the integrated circuits.	[SU1] Assessment of task fulfilment
Subject contents	<p>Basic families of integrated circuits - classifications based on application types, devices used for constructions, substrates and technologies. Application specific integrated circuits - full custom, gate arrays, standard cells.</p> <p>Scaling rules of MOS transistors in integrated circuits. Effect of scaling on operation speed, packing density, power consumption and technological yield.</p> <p>Extraction of MOS FET model parameters for electrical circuit simulation with programs like SPICE. Special circuits like ring oscillators.</p> <p>Introduction to photolithography in microelectronics. Advantages and disadvantages of electron beam lithography.</p> <p>Substrates for fabrication of integrated circuits.</p> <p>Si oxidation - for fabrication of gates and isolation in CMOS technology.</p> <p>Selective doping of silicon - diffusion from gas phase and ion implantation.</p> <p>Etching of materials used in semiconductor technology.</p> <p>Physical vapor deposition of layers. Properties of metal-semiconductor contacts and of conducting paths.</p> <p>Chemical deposition, forming and application of layers in semiconductor technology - SiO₂, SiN, metals, oxides of high dielectric constants, materials of low dielectric constants. Deposition of layers with a single atomic layer precision – principles and application of ALD. Example technologies of HfO₂, Al₂O₃, ZrO₂.</p> <p>Epitaxy - contemporary applications in microelectronics.</p> <p>Device integration in contemporary, advanced MOS technologies. Layout of inverter gate elements, photomask sets and sequences of fabrication steps, including process flows for FinFETs.</p> <p>Logic gates in silicon technologies: CMOS, BiCMOS, ECL. Construction, operation, element layouts, designing problems. Influence of parasitic elements. Logic gates in III-V technologies.</p> <p>Sequential logic circuits in silicon technologies: CMOS, BiCMOS, ECL. Construction, operation, element layouts, designing problems.</p> <p>Memory circuits of RAM, ROM and FLASH types in silicon technologies: CMOS, BiCMOS, ECL. Construction, operation, element layouts, designing problems. Possibilities of integration of memory circuits with logic circuits.</p> <p>Integration of devices in amorphous and polycrystalline materials - like for liquid crystal displays and for photovoltaics and optoelectronics.</p> <p>Integrated circuits in organic semiconductors - properties and methods of fabrication. Prospectives of integration and application.</p> <p>Prospectives and problems of integration of mesoscopic devices operating with two- one- or zero-dimensional physics. Prospectives of application of new materials like graphen.</p>		
Prerequisites and co-requisites			

